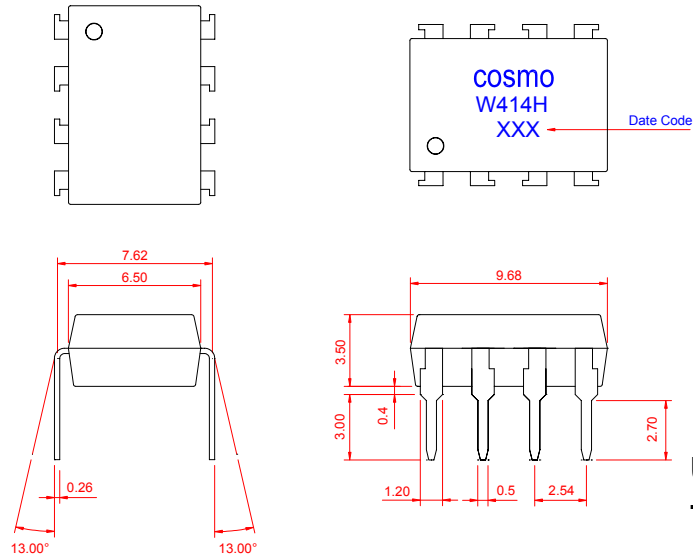


PRODUCT SPECIFICATION

DATE : 03/01/2005

cosmo ELECTRONICS CORPORATION	SOLID STATE RELAY - MOSFET OUTPUT KAQW414H	Preliminary	REV. 0
		SHEET 1 OF 7	

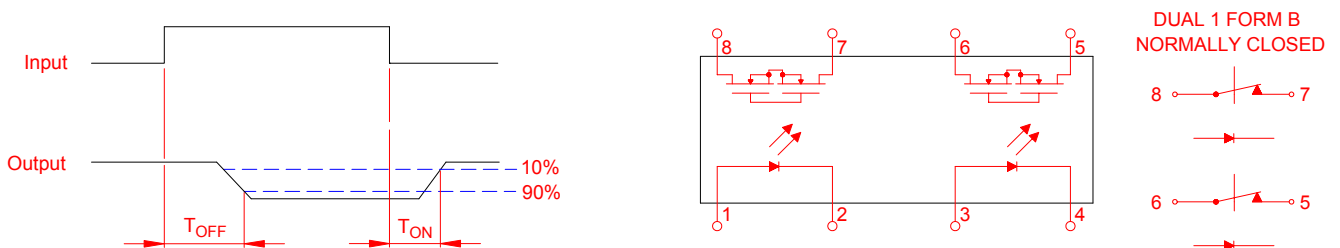
● OUTSIDE DIMENSION :



Unit : mm

Tolerance : $\pm 0.2\text{mm}$

● Operate / Reverse time



● Absolute Maximum Ratings

($T_a = 25^\circ\text{C}$)

Emitter (Input)		Detector (Output)	
Reverse Voltage		5.0V	Output Breakdown Voltage
Continuous Forward Current		50mA	Continuous Load Current
Peak Forward Current		1A	Power Dissipation
Power Dissipation		100mW	
Derate Linearly from 25°C		1.3mW/ $^\circ\text{C}$	
General Characteristics			
Isolation Test Voltage		5000VACrms	Storage Temperature Range
Isolation Resistance			Operating Temperature Range ...
$V_{io} = 500\text{V}$, $T_a = 25^\circ\text{C}$		$\geq 10^{10}\Omega$	Junction Temperature
Total Power Dissipation		550mW	Soldering Temperature ,
Derate Linearly from 25°C		2.5mW/ $^\circ\text{C}$	2mm from case , 10 sec
			260 $^\circ\text{C}$

PRODUCT SPECIFICATION

DATE : 03/01/2005

cosmo ELECTRONICS CORPORATION	SOLID STATE RELAY - MOSFET OUTPUT KAQW414H	Preliminary	REV. 0
		SHEET 2 OF 7	

● Electro-optical Characteristics

(Ta=25°C)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit.
Emitter (Input)						
Forward Voltage	V_F	$I_F=10\text{mA}$		1.2	1.5	V
Operation Input Current	$I_{F\text{OFF}}$	$V_L=\pm 20\text{V}$, $I_L \leq 5\mu\text{A}$			5.0	mA
Recovery Input Current	$I_{F\text{ON}}$	$V_L=\pm 20\text{V}$, $I_L=100\text{mA}$, $t=10\text{ms}$	0.2			mA
Detector (Output)						
Output Breakdown Voltage	V_B	$I_B=50\mu\text{A}$, $I_F=10\text{mA}$	400			V
Output Off-State Leakage	$I_{T\text{OFF}}$	$V_T=100\text{V}$, $I_F=10\text{mA}$		0.2	2	μA
I/O Capacitance	C_{ISO}	$I_F=0$, $f=1\text{MHz}$		6		pF
ON Resistance	R_{ON}	$I_L=100\text{mA}$, $I_F=0\text{mA}$		40	50	Ω
Reverse (ON) Time	T_{ON}	$I_F=10\text{mA}$, $V_L=\pm 20\text{V}$ $t=10\text{ms}$, $I_L=\pm 100\text{mA}$		0.6	1.5	ms
Operate (OFF) Time	T_{OFF}			0.3	1.0	ms

● Schematic and Wiring Diagrams

Schematic	Output Configuration	Load	Connection	Wiring Diagrams
	2b	AC/DC	-	(1) Two Independent 1 Form B use (2) 2 Form B use

PRODUCT SPECIFICATION

DATE : 03/01/2005

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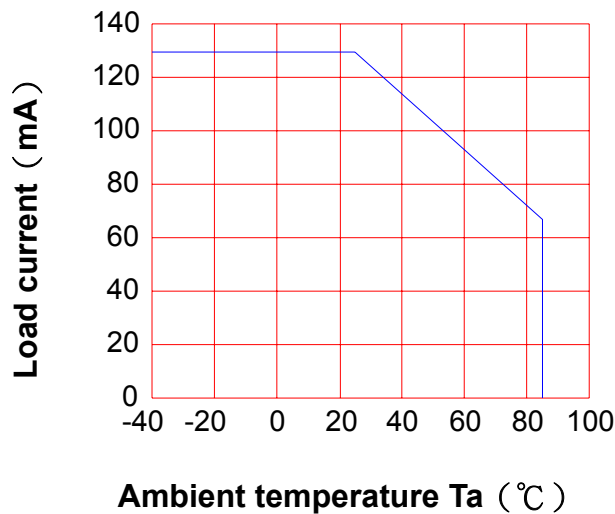
SOLID STATE RELAY - MOSFET OUTPUT
KAQW414H

Preliminary
SHEET 3 OF 7

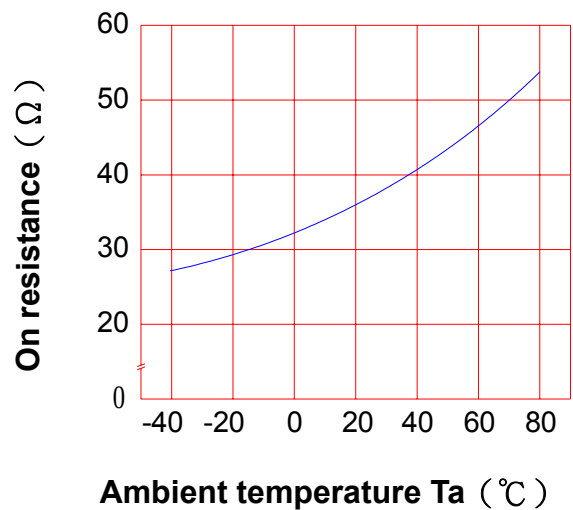
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● Data Curve

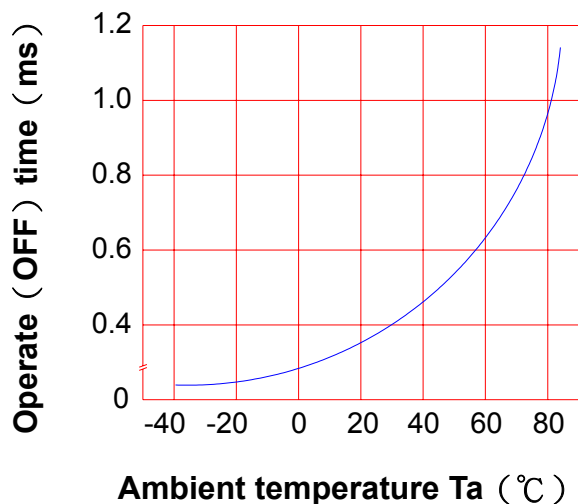
Load current vs. ambient temperature
Allowable ambient Temperature :
-40°C to +85°C



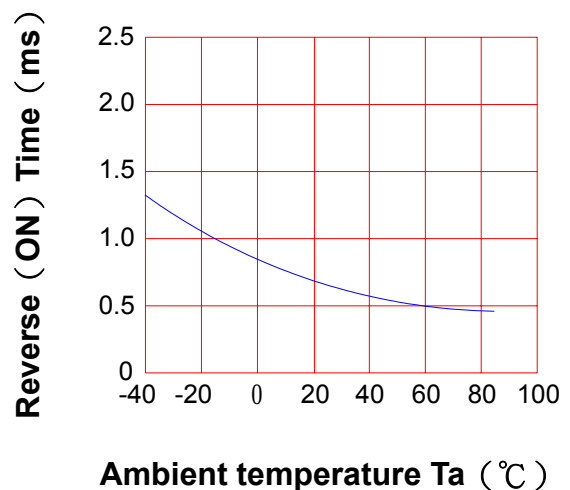
On resistance vs. ambient temperature
across terminals 5,7 and 6,8 pin
LED current : 5mA
Continuous load current : 130mA (DC)



Operate (OFF) time vs.
ambient temperature
Load voltage 400V (DC)
LED current : 5mA
Continuous load current : 130mA (DC)



Reverse (ON) time vs.
ambient temperature
Load voltage 400V (DC)
LED current : 5mA
Continuous load current : 130mA (DC)



PRODUCT SPECIFICATION

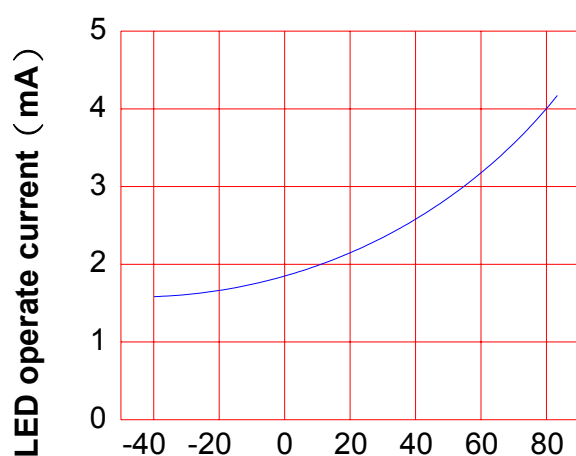
DATE : 03/01/2005

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		SHEET 4 OF 7	

LED operate current vs.
ambient temperature

Load Voltage : 400V (DC)

Continuous load current : 130mA (DC)

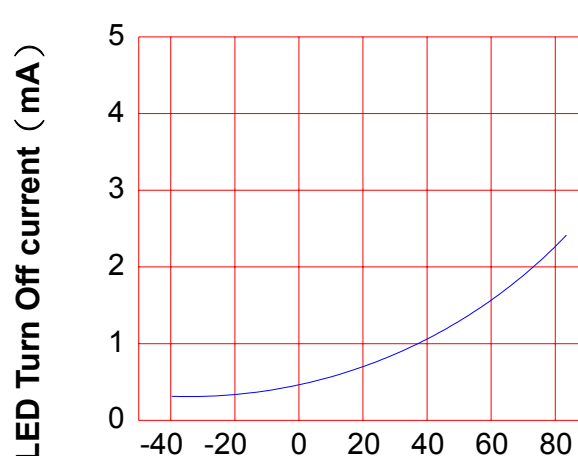


Ambient temperature Ta (°C)

LED Turn Off current vs.
ambient temperature

Load Voltage : 400V (DC)

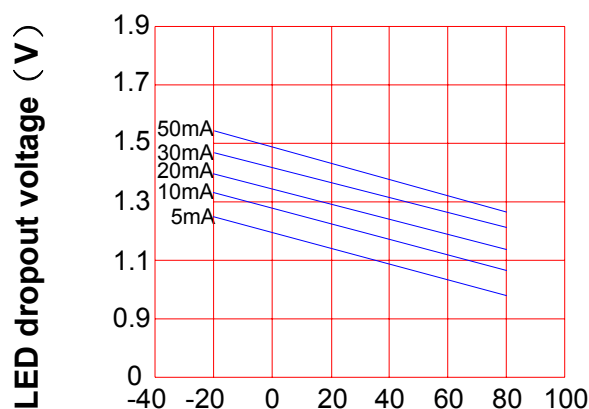
Continuous load current : 130mA (DC)



Ambient temperature Ta (°C)

LED dropout voltage vs.
ambient temperature

LED current : 5 to 50mA

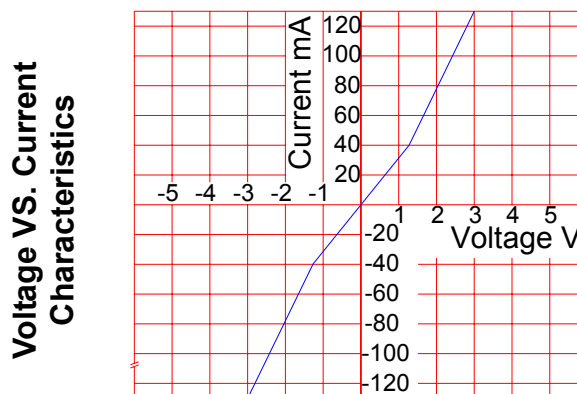


Ambient temperature Ta (°C)

Voltage vs. current characteristics
of output at MOSFET portion

Measured portion : across terminals
5,7 and 6,8 pin

Ambient temperature : 25°C



Ambient temperature : 25°C

PRODUCT SPECIFICATION

DATE : 03/01/2005

cosmo ELECTRONICS CORPORATION	SOLID STATE RELAY - MOSFET OUTPUT KAQW414H	Preliminary	REV. 0
		SHEET 5 OF 7	

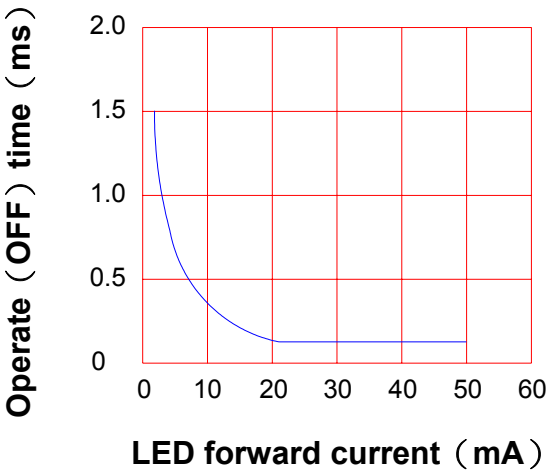
LED forward current vs. Operate (OFF) time

Across terminals 5,7 and 6,8 pin

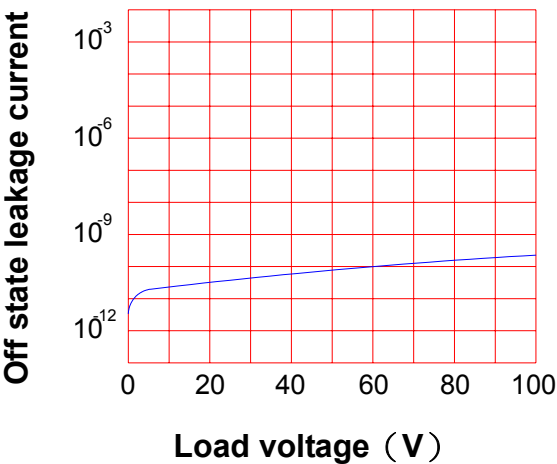
Load voltage : 400V (DC)

Continuous load current : 130mA (DC)

Ambient temperature : 25°C



Off state leakage current
Across terminals 5,7 and 6,8 pin
Ambient temperature : 25°C



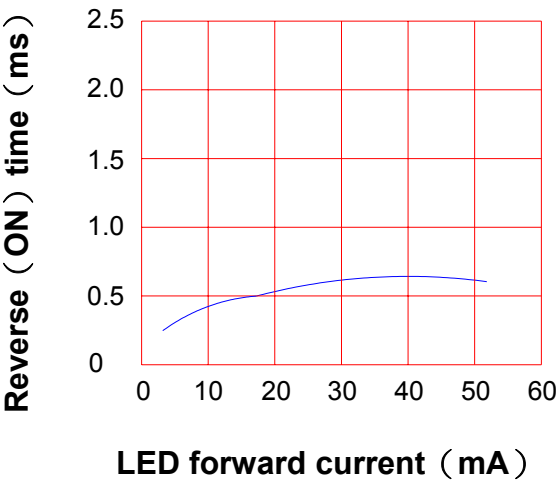
LED forward current vs. reverse (ON) time

Across terminals 5,7 and 6,8 pin

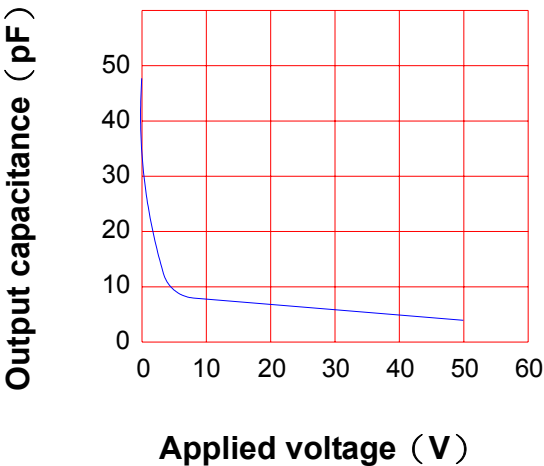
Load voltage : 400V (DC)

Continuous load current : 130mA (DC)

Ambient temperature : 25°C



Applied voltage vs. output capacitance
Across terminals 5,7 and 6,8 pin
Frequency : 1MHz
Ambient temperature : 25°C



PRODUCT SPECIFICATION

DATE : 03/01/2005

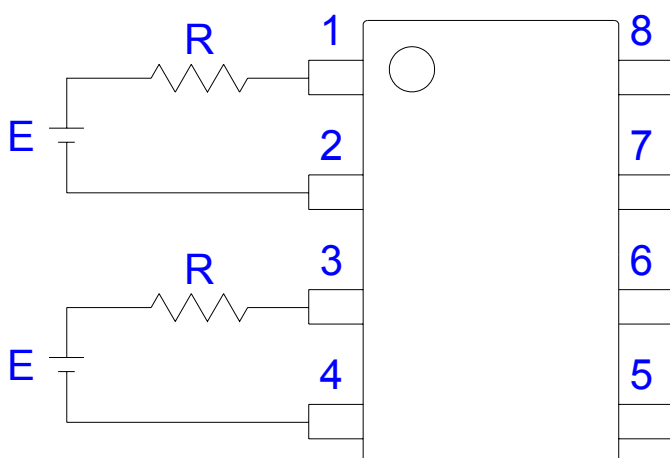
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		SHEET 6 OF 7	

● USING METHODS

Examples of resistance value to
control LED forward current (I_F)

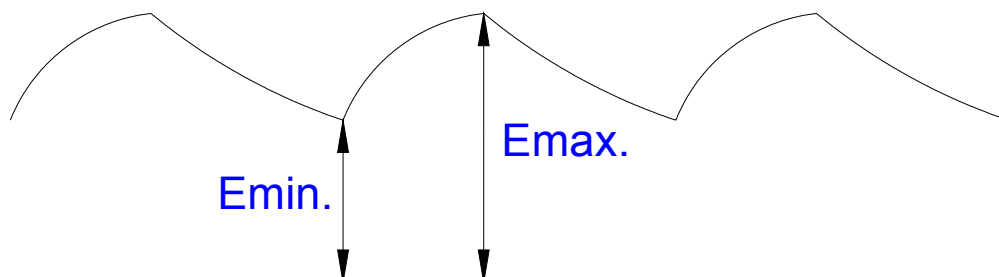
SSR-MOSFET OUTPUT

($I_F=5\text{mA}$)



E	R
3.3V	Approx. 330 Ω
5V	Approx. 640 Ω
12V	Approx. 1.9K Ω
15V	Approx. 2.5K Ω
24V	Approx. 4.1K Ω

- (1) LED forward current must be more than 5mA , at E min.
- (2) LED forward current must be less than 50mA , at E max.



PRODUCT SPECIFICATION

DATE : 03/01/2005

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SOLID STATE RELAY - MOSFET OUTPUT
KAQW414H

Preliminary
SHEET 7 OF 7

REV.
0

● USING METHODS

Regulate the spike voltage generated on the inductive load as follows :

